RELIABILITY REPORT

FOR

MAX815TxxA

PLASTIC ENCAPSULATED DEVICES

November 28, 2001

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

Jim Pedicord Quality Assurance Reliability Lab Manager Reviewed by

Bryan J. Preeshl Quality Assurance Executive Director

Conclusion

The MAX815T successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX815T is a high-accuracy microprocessor (μP) supervisory circuit that provides power-on reset, watchdog, and power-fail functions. It eliminates manual trimming and improves reliability in critical applications needing high-accuracy reset thresholds. The /RESET output is guaranteed to be in the correct state for V_{CC} down to 1V. The reset comparator is designed to ignore fast transients on V_{CC} . Reset thresholds are available for operation with a variety of 3V and 5V supply voltages.

A 75µA maximum supply current makes the MAX815T ideal for use in portable equipment.

B. Absolute Maximum Ratings

<u>ltem</u>	<u>Rating</u>
Terminal Voltage (with respect to GND)	-
V_{cc}	-0.3V to +6.0V
All Other Pins (Note 1)	$-0.3V$ to $(V_{CC} + 0.3V)$
Terminal Current (PFI, RESET IN, /MR)	10mA
Terminal Current (all other pins)	20mA
Storage Temp.	-65°C to +160°C
Lead Temp. (10 sec.)	+300°C
Power Dissipation	
8-Pin NSO	471mW
8-Pin PDIP	727mw
Derates above +70°C	
8-Pin NSO	5.88mW/°C
8-Pin PDIP	9.09mW/°C

Note 1: Applies if /WDO is externally connected to /MR or if /MR is externally driven.

II. Manufacturing Information

A. Description/Function: +/- 1% Accuracy, Low-Power, +3V/ +5V uP Supervisory Circuit

B. Process: SG3 (Standard 3 micron silicon gate CMOS)

C. Number of Device Transistors: 744

D. Fabrication Location: California or Oregon, USA

E. Assembly Location: Philippines, Malaysia or Thailand

F. Date of Initial Production: May, 1996

III. Packaging Information

A. Package Type: 16-Lead NSO 16-Lead PDIP

B. Lead Frame: Copper Copper

C. Lead Finish: Solder Plate Solder Plate

D. Die Attach: Silver-filled Epoxy Silver-filled Epoxy

E. Bondwire: Gold (1.3 mil dia.) Gold (1.3 mil dia.)

F. Mold Material: Epoxy with silica filler Epoxy with silica filler

G. Assembly Diagram: Buildsheet # 05-1701-0216 Buildsheet # 05-1701-0215

H. Flammability Rating: Class UL94-V0 Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-A112: Level 1 Level 1

IV. Die Information

A. Dimensions: 85x110 mils

B. Passivation: SiN/SiO (nitride/oxide)

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: 3 microns (as drawn)

F. Minimum Metal Spacing: 3 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Reliability Lab Manager)
Bryan Preeshl (Executive Director)

Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{6.21}{192 \times 4389 \times 1200} \text{ (Chi square value for MTTF upper limit)}$$

Temperature Acceleration factor assuming an activation energy of 0.8eV

 $\lambda = 3.07 \times 10^{-9}$
 $\lambda = 3.07 \text{ F.I.T. (60\% confidence level @ 25°C)}$

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on any lot that exceeds this reliability control level. Attached Burn-In Schematic (Spec. # 06-5086) shows the static Burn-In circuit. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (RR-1L).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85° C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The PW56-7 die type has been found to have all pins able to withstand a transient pulse of \pm 1000V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of \pm 250mA and/or \pm 20V.

Table 1
Reliability Evaluation Test Results
MAX815TxxA

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	t (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		1200	2
Moisture Testin	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 96hrs.	DC Parameters & functionality	PDIP NSO	1549 1819	1 15
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ress (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters		77	0

Note 1: Life Test Data may represent plastic D.I.P. qualification lots for the Small Outline package.

Note 2: Generic Package/Process data

Attachment #1

TABLE II. Pin combination to be tested. 1/2/

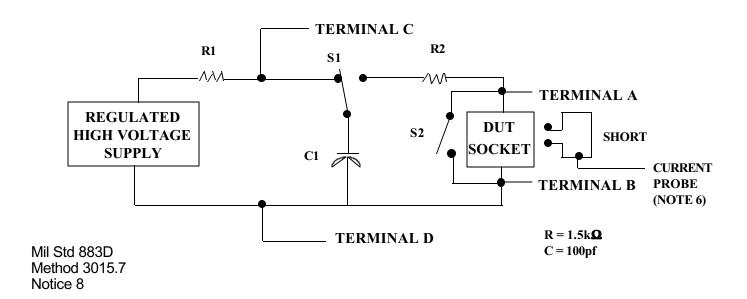
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} 3/	All V _{PS1} pins
2.	All input and output pins	All other input-output pins

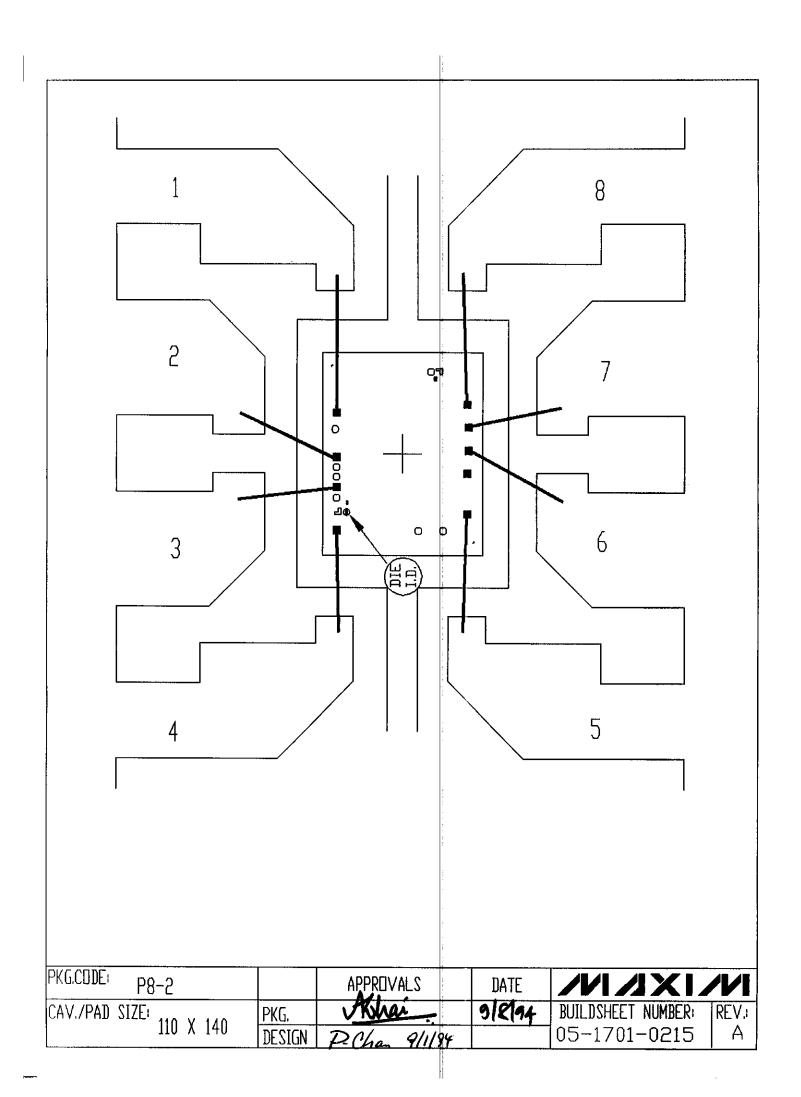
- 1/ Table II is restated in narrative form in 3.4 below.
- $\overline{2}$ No connects are not to be tested.
- 3/ Repeat pin combination I for each named Power supply and for ground

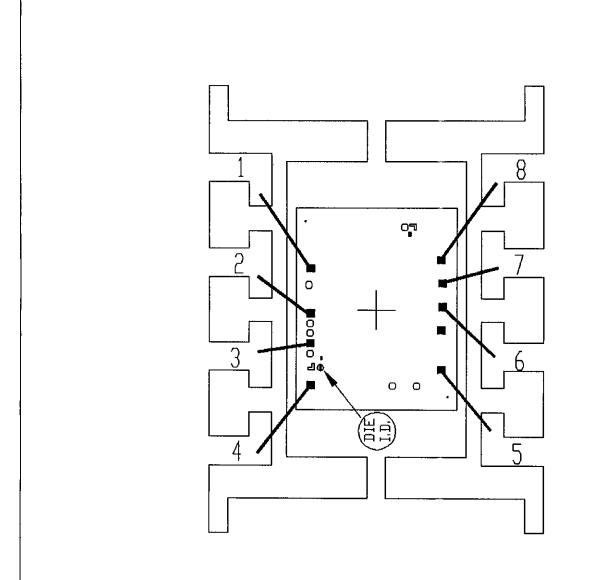
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{S1}, or V_{S2} or V_{S3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.







PKG.CODE: S8-5		APPROVALS	DATE	NIXI	1/1
CAV./PAD SIZE:	PKG.	VKMai	9/2/94	BUILDSHEET NUMBER:	REV.:
95 X 155	DESIGN	P. Chan 9/1/84		05-1701-0216	Α

